

CLAIMS

WHAT IS CLAIMED:

1. A built-in self-test controller, comprising:
a plurality of alternative memory built-in self-test state machines; and
a memory built-in self-test engine operating a predetermined one of the memory built-in self-test state machines.

2. The built-in self-test controller of claim 1, further comprising a logic built-in self-test engine.

3. The built-in self-test controller of claim 1, further comprising a memory built-in self-test signature generated by an execution of the memory built-in self-test.

4. The built-in self-test controller of claim 3, wherein the memory built-in self-test signature includes the results of at least one paranoid check.

5. The built-in self-test controller of claim 3, wherein the memory built-in self-test signature includes a bit indicating whether a memory built-in self-test is done.

6. The built-in self-test controller of claim 1, wherein at least one of the memory built-in self-test state machines comprises:

- a reset state entered upon receipt of an external reset signal;
- an initiate state entered from the reset state upon receipt of at least one of a memory built-in self-test run signal and a memory built-in self-test select signal;
- a flush state entered from the initiate state upon the initialization of components and signals in the memory built-in self-test domain in the initiate state;
- a test state entered into from the flush state upon completing a flush of a plurality of memory components to a known state; and
- a done state entered into upon completing the test of each of the memory components in the memory built-in self-test.

7. A built-in self-test controller, comprising:
means for implementing a plurality of states in a plurality of sets in a memory built-in self-test; and

means for operating a predetermined one of the sets in the memory built-in self-test.

8. The built-in self-test controller of claim 7, further comprising a logic built-in self-test engine.

9. The built-in self-test controller of claim 7, further comprising a memory built-in self-test signature generated by an execution of the memory built-in self-test.

10. The built-in self-test controller of claim 7, wherein at least one of the sets comprises:

a reset state entered upon receipt of an external reset signal;
an initiate state entered from the reset state upon receipt of at least one of a memory built-in self-test run signal and a memory built-in self-test select signal;
a flush state entered from the initiate state upon the initialization of components and signals in the memory built-in self-test domain in the initiate state;
a test state entered into from the flush state upon completing a flush of a plurality of memory components to a known state; and
a done state entered into upon completing the test of each of the memory components in the memory built-in self-test.

11. An integrated circuit device, comprising:

a plurality of memory components;
a testing interface; and
a built-in self-test controller controlled through the testing interface, comprising:
a plurality of alternative memory built-in self-test state machines; and
a memory built-in self-test engine operating a predetermined one of the memory built-in self-test state machines.

12. The integrated circuit device of claim 11, further comprising a logic built-in self-test engine.

13. The integrated circuit device of claim 11, further comprising a memory built-in self-test signature register generated by an execution of the memory built-in self-test.

14. The integrated circuit device of claim 13, wherein the memory built-in self-test signature includes the results of at least one paranoid check.

1 15. The integrated circuit device of claim 13, wherein the memory built-in self-
2 test signature includes a bit indicating whether a memory built-in self-test is done.

1 16. The integrated circuit device of claim 11, wherein at least one of the memory
2 built-in self-test state machines comprises:

- 3 a reset state entered upon receipt of an external reset signal;
4 an initiate state entered from the reset state upon receipt of at least one of a memory
5 built-in self-test run signal and a memory built-in self-test select signal;
6 a flush state entered from the initiate state upon the initialization of components and
7 signals in the memory built-in self-test domain in the initiate state;
8 a test state entered into from the flush state upon completing a flush of a plurality of
9 memory components to a known state; and
10 a done state entered into upon completing the test of each of the memory components
11 in the memory built-in self-test.

1 17. The integrated circuit device of claim 11, wherein the memory components
2 include a synchronous random access memory device.

1 18. The integrated circuit device of claim 11, wherein testing interface comprises
2 a Joint Test Action Group tap controller.

- 1 19. An integrated circuit device, comprising:
2 a plurality of memory components;
3 a testing interface; and
4 a built-in self-test controller controlled through the testing interface, comprising:
5 means for implementing a plurality of states in a plurality of sets in a memory
6 built-in self-test; and
7 means for operating a predetermined one of the sets in the memory built-in
8 self-test.

1 20. The integrated circuit device of claim 19, further comprising a logic built-in
2 self-test engine.

1 21. The integrated circuit device of claim 19, further comprising a memory built-
2 in self-test signature register generated by an execution of the memory built-in self-test.

1 22. The integrated circuit device of claim 19, wherein at least one of the sets
2 comprises:

3 a reset state entered upon receipt of an external reset signal;

4 an initiate state entered from the reset state upon receipt of at least one of a memory
5 built-in self-test run signal and a memory built-in self-test select signal;

6 a flush state entered from the initiate state upon the initialization of components and
7 signals in the memory built-in self-test domain in the initiate state;

8 a test state entered into from the flush state upon completing a flush of a plurality of
9 memory components to a known state; and

10 a done state entered into upon completing the test of each of the memory components
11 in the memory built-in self-test.

12 23. The integrated circuit device of claim 19, wherein the memory components
13 include a synchronous random access memory device.

14 24. The integrated circuit device of claim 19, wherein testing interface comprises
15 a Joint Test Action Group tap controller.

16 25. A method for performing a built-in self-test on an integrated circuit device,
17 comprising:

18 externally resetting a predetermined one of a plurality of memory state machines in a
19 memory built-in self-test controller;

20 performing a memory built-in self-test utilizing the reset memory state machine ; and
21 obtaining the results of the performed memory built-in self-test.

22 26. The method of claim 25, wherein performing the memory built-in self-test
23 includes:

24 initiating a plurality of components and signals in a memory built-in self-test domain
25 of the dual mode built-in self-test controller upon receipt of at least one of a
26 memory built-in self-test run signal and a memory built-in self-test select
27 signal;

28 flushing the contents of a plurality of memory components to a known state after
29 initialization of the components and the signals in the memory built-in self-test
30 domain; and

testing the flushed memory components.

27. The method of claim 26, wherein performing the memory built-in self-test further includes at least one of:

storing the results of the memory built-in self-test in a memory built-in self-test signature register;

storing the results of at least one paranoid check in the memory built-in self-test signature register;

setting a bit in the memory built-in self-test signature register indicating whether the memory built-in self-test is done.

28. The method of claim 25, further comprising:

externally resetting a logic state machine;

performing a logic built-in self-test utilizing the reset memory state machine; and
obtaining the results of the performed logic built-in self-test.

29. The method of claim 25, wherein obtaining the results includes receiving the results as the memory built-in self-test is performed or reading the stored results from a register.

30. A method for testing an integrated circuit device, comprising:

interfacing the integrated circuit device with a tester;

externally resetting a built-in self-test controller, including:

externally resetting a predetermined one of a plurality of memory state machines;

performing a memory built-in self-test from the built-in self-test controller;

obtaining the results of the performed memory built-in self-test.

31. The method of claim 30, wherein performing the memory built-in self-test includes:

initiating a plurality of components and signals associated with the memory built-in self-test upon receipt of at least one of a memory built-in self-test run signal and a memory built-in self-test select signal;

flushing the contents of a plurality of memory components to a known state after the initialization of the associated components and the signals; and

testing the flushed memory components.

32. The method of claim 31, wherein performing the memory built-in self-test further includes at least one of:

storing the results of the memory built-in self-test in a memory built-in self-test signature register;

storing the results of at least one paranoid check in the memory built-in self-test signature register;

setting a bit in the memory built-in self-test signature register indicating whether the memory built-in self-test is done.

33. The method of claim 30, wherein obtaining the results includes reading a memory built-in self-test signature.

34. The method of claim 30, wherein interfacing the integrated circuit device with the tester includes employing Joint Test Action Group protocols.

35. The method of claim 30, wherein externally resetting the built-in self-test controller includes externally resetting a logic state machines' and wherein the method further comprises performing a memory built-in self-test from the built-in self-test controller.

36. The method of claim 30, wherein obtaining the results includes receiving the results as the memory built-in self-test is performed or reading the stored results from a register.